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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
10/090,277	03/04/2002	Maximillian Fleischer	A35006 (071308.0294)	A35006 (071308.0294) 4174	
21003	7590 08/25/2004		EXAMINER		
BAKER & BOTTS 30 ROCKEFELLER PLAZA			SIEFKE, SAMUEL P		
NEW YORK, NY 10112			ART UNIT	PAPER NUMBER	
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DATE MAILED: 08/25/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)			
		10/090,277	FLEISCHER ET AL.			
Office Action Summary		Examiner	Art Unit			
	•	Samuel P Siefke	1743			
To	The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply					
THE MAI - Extension after SIX (- If the perio - If NO perio - Failure to Any reply	TENED STATUTORY PERIOD FOR REPLY ILLING DATE OF THIS COMMUNICATION. so of time may be available under the provisions of 37 CFR 1.13 (6) MONTHS from the mailing date of this communication. od for reply specified above is less than thirty (30) days, a reply od for reply is specified above, the maximum statutory period w reply within the set or extended period for reply will, by statute, received by the Office later than three months after the mailing tent term adjustment. See 37 CFR 1.704(b).	66(a). In no event, however, may a reply be tir within the statutory minimum of thirty (30) da ill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	mely filed /s will be considered timely. If the mailing date of this communication.			
Status						
2a)☐ Thi 3)☐ Sin	sponsive to communication(s) filed ons action is FINAL . 2b) This ace this application is in condition for allowant sed in accordance with the practice under E	action is non-final. ice except for formal matters, pro				
Disposition	of Claims					
4a) 5)□ Cla 6)⊠ Cla 7)⊠ Cla	tim(s) <u>1-10</u> is/are pending in the application. Of the above claim(s) is/are withdraw im(s) is/are allowed. im(s) <u>1,2 and 4-10</u> is/are rejected. im(s) <u>3</u> is/are objected to. im(s) are subject to restriction and/or					
Application I	Papers					
9)☐ The 10)☐ The App Rep	specification is objected to by the Examiner drawing(s) filed on is/are: a) accellicant may not request that any objection to the diacement drawing sheet(s) including the correction oath or declaration is objected to by the Examiner	pted or b) objected to by the E rawing(s) be held in abeyance. See on is required if the drawing(s) is obj	e37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).			
Priority unde	er 35 U.S.C. § 119					
a) A 1. 2. 3.	Certified copies of the priority documents Certified copies of the priority documents	have been received. have been received in Application by documents have been received (PCT Rule 17.2(a)).	on No d in this National Stage			
Notice of D Information Paper No(s J.S. Patent and Trademai		4) Interview Summary (Paper No(s)/Mail Da 5) Notice of Informal Pa 6) Other:	(PTO-413) te atent Application (PTO-152)			
PTOL-326 (Rev. 1-	04) Office Acti	on Summary F	Part of Paper No./Mail Date 062404			

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DETAILED ACTION

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claim 2 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. Claim should read, "wherein the gas sensitive layer comprises a polymer and the polymers are a polysiloxane or a polysilosequioxane derivative."

Claim 3 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. Claim should read, "wherein the polymer is a polysilsesquioxane derivative and the polysilsesquioxane derivative is polycyclopenylsisesquioxane."

Claim 4 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. Claim should read, "wherein the gas sensitive layer comprises a metal oxide and the metal oxide is scandium oxide."

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

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A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims **1,4,5** are rejected under 35 U.S.C. 102(b) as being anticipated by Tsutsumi et al. (USPN 3,663,870).

Tsutsumi discloses a semiconductor device passivated with a rare earth oxide layer. The semiconductor device comprises a gas sensitive field effect transistor that comprises a substrate (fig. 6 ref. 71) having a source (72) and a drain (73) areas and at least one gate electrode (G in fig 6) associated with a gas sensitive layer comprising a inorganic metal oxide (scandium oxide; col. 5, lines 70-73; col. 2, lines 26-66) applied to the substrate (col. 6, line 66- col. 7, line 39). The semiconductor further comprises an electrical heater (45 and 46; col. 3, lines 26-29). The semiconductor further comprises a plurality of different gas sensitive layers (col.6, lines 18-23).

Claims **1,2** are rejected under 35 U.S.C. 102(b) as being anticipated by DE 4028062.

DE '062 discloses a gas sensor for measuring concentration of organic vapor in aromatic mixtures with polysiloxane absorbent contiguous substance forming ions or disposed over gate with wide sensitivity range for alcohols etc. (abstract). The sensor comprises a semiconductor substrate (2) with source (3) and drain (4) and an insulating film (5) on the substrate covered with a metal film with breaks (6) and gate (7). A change in the threshold potential is used as sensor signal. Outside of the gate (7) is covered with a layer (8) of an adsorbent (I) for the target molecules of vapor of organic molecules contiguous substrate (II) producing ions or dipoles (abstract).

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Claims 1, 6, 7, 10 are rejected under 35 U.S.C. 102(b) as being anticipated Inami et al. (USPN 4,638,346).

Inami discloses a field effect transistor type moisture sensor that comprises a field effect transistor device incorporated with a moisture sensitive means, the electrostatic capacity or the electrical conductivity of which varies with the absorption and the desorption of water vapor or moisture, wherein the moisture sensitive means is disposed on a gate insulating film of the field effect transistor device to form an electrode structure (abstract). The sensor comprises a source (2) and a drain (3) on silicon substrate (1). The surface of the silicon substrate is covered with a silicon dioxide film having through holes for the source (2) and the drain (3). Double layers of the silicon dioxide film (5) and a silicon nitride film on the silicon substrate form between the source (2) and drain (3) a gate insulating film (100) (col. 4, lines 18-41). The moisture sensor containing a metal oxide film has an excellent heat resistance and responds rapidly and has a high temperature resistance coefficient, and a gas insensitive transistor for compensating for temperature effects (col. 2, lines 35-41; col. 3, lines 45-49; col. 4, lines 61-68).

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The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

The factual inquiries set forth in *Graham* v. *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

- 1. Determining the scope and contents of the prior art.
- 2. Ascertaining the differences between the prior art and the claims at issue.
- Resolving the level of ordinary skill in the pertinent art.
- 4. Considering objective evidence present in the application indicating obviousness or nonobviousness.

Claims **7, 8,9** are rejected under 35 U.S.C. 103(a) as being unpatentable over DE 4028062 in view of Inami et al. (USPN 4,638,346).

DE '062 discloses a gas sensor for measuring concentration of organic vapor in aromatic mixtures with polysiloxane absorbent contiguous substance forming ions or disposed over gate with wide sensitivity range for alcohols.

DE '062 does not teach the specific use of polycyclopentylsilsesquioxane or the use of a moisture sensitive layer.

Inami discloses a field effect transistor type moisture sensor that comprises a field effect transistor device incorporated with a moisture sensitive means, the electrostatic capacity or the electrical conductivity of which varies with the absorption and the desorption of water vapor or moisture, wherein the moisture sensitive means is disposed on a gate insulating film of the field effect transistor device to form an

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electrode structure. It would have been obvious to one having an ordinary skill in the art to modify DE '062 to include the moisture sensitive layer of Inami to provide a more precise and balanced measurement because moisture interferes with alcohol detection (abstract DE '062) is known in the art.

Allowable Subject Matter

Claim 3 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims. The prior art does not teach or fairly suggest a gas sensitive layer comprising a polycyclopentylsilsesquioxane.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Samuel P Siefke whose telephone number is 571-272-1262. The examiner can normally be reached on M-F 7:00am-5:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Jill A. Warden can be reached on 571-272-1700. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Sam P. Siefke

June 24, 2004

/Jill Warden
Supervisory Patent Examiner
Technology Center 1700